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With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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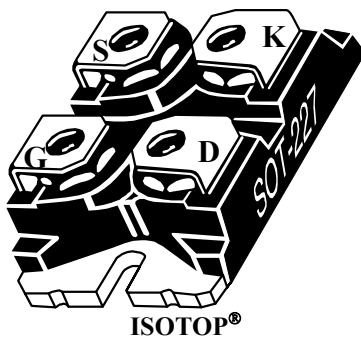
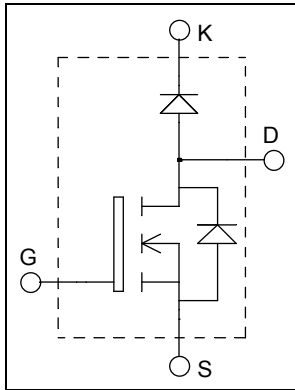
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**ISOTOP[®] Boost chopper
SiC MOSFET + SiC chopper diode
Power module**

**$V_{DSS} = 1200V$
 $R_{DS(on)} = 17m\Omega \text{ max @ } T_j = 25^\circ C$
 $I_D = 143A \text{ @ } T_c = 25^\circ C$**



Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction
- Brake switch

Features

- **SiC Power MOSFET**
 - Low $R_{DS(on)}$
 - High temperature performance
- **SiC Schottky Diode**
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature Independent switching behavior
 - Positive temperature coefficient on VF
- ISOTOP[®] Package (SOT-227)
- Very low stray inductance
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of V_{CEsat}
- RoHS Compliant

All ratings @ $T_j = 25^\circ C$ unless otherwise specified

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V_{DSS}	Drain - Source Breakdown Voltage	1200	V
I_D	Continuous Drain Current	$T_c = 25^\circ C$	143
		$T_c = 80^\circ C$	108
I_{DM}	Pulsed Drain current	280	
V_{GS}	Gate - Source Voltage	-10/+25	V
$R_{DS(on)}$	Drain - Source ON Resistance	17	m Ω
P_D	Maximum Power Dissipation	$T_c = 25^\circ C$ 600	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

Electrical Characteristics

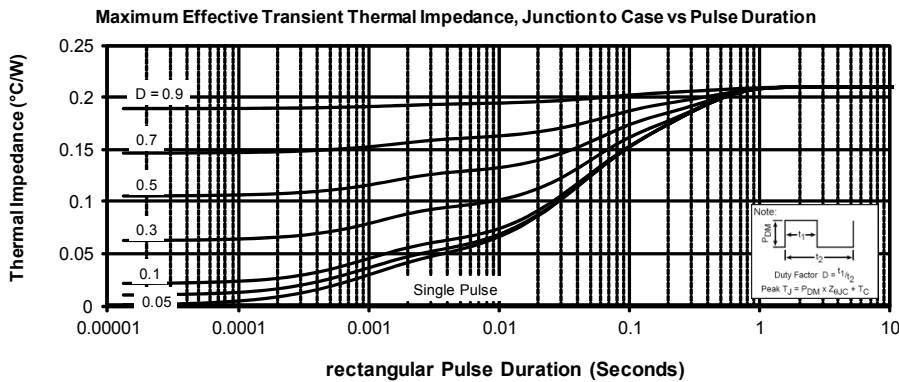
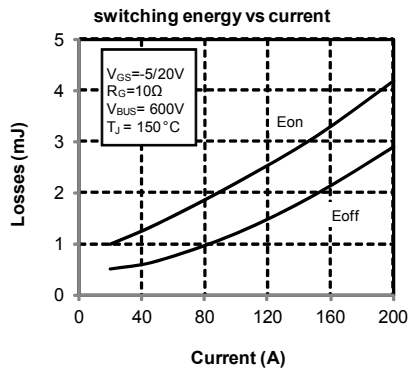
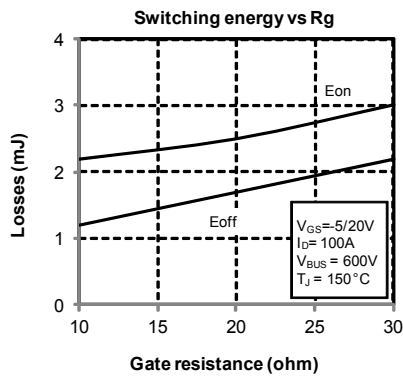
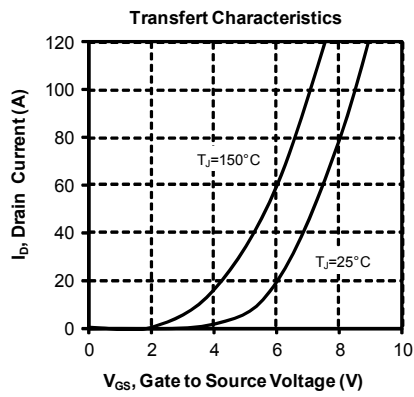
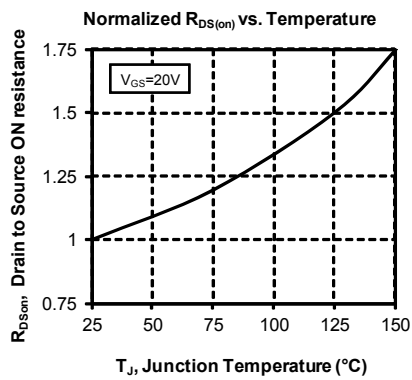
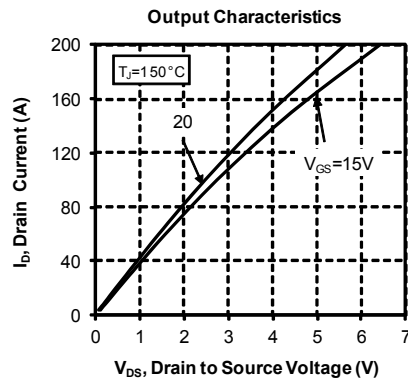
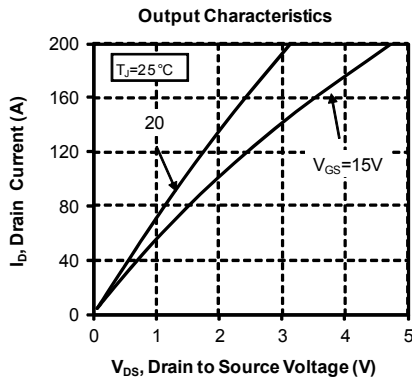
<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>	<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1200V$		20	200	μA
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 20V$ $I_D = 100A$	$T_j = 25^\circ C$ $T_j = 150^\circ C$	12.5 22	17 32	$m\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 2mA$	1.9	2.3		V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = 20V, V_{DS} = 0V$			1	μA

Dynamic Characteristics

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>	<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
C_{iss}	Input Capacitance	$V_{GS} = 0V$		5960		pF
C_{oss}	Output Capacitance	$V_{DS} = 1000V$		440		
C_{rss}	Reverse Transfer Capacitance	$f = 1MHz$		46		
Q_g	Total gate Charge	$V_{GS} = -2/+20V$		360		nC
Q_{gs}	Gate – Source Charge	$V_{Bus} = 800V$		64		
Q_{gd}	Gate – Drain Charge	$I_D = 100A$		126		
$T_{d(on)}$	Turn-on Delay Time	$V_{GS} = -2/+20V$ $V_{Bus} = 800V$ $I_D = 100A$ $R_L = 8\Omega; R_G = 10\Omega$		21		ns
T_r	Rise Time			19		
$T_{d(off)}$	Turn-off Delay Time			50		
T_f	Fall Time			30		
E_{on}	Turn on Energy	Inductive Switching $V_{GS} = -5/+20V$ $V_{Bus} = 600V$	$T_j = 150^\circ C$	2.2		mJ
E_{off}	Turn off Energy	$I_D = 100A$ $R_G = 10\Omega$	$T_j = 150^\circ C$	1.2		
R_{thJC}	Junction to Case Thermal Resistance				0.21	$^\circ C/W$

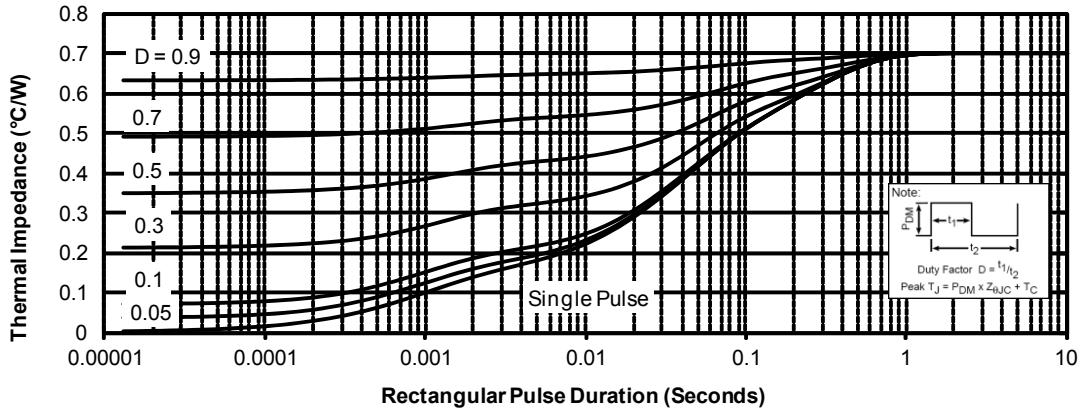
SiC chopper diode ratings and characteristics

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>	<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
V_{RRM}	Maximum Peak Repetitive Reverse Voltage		1200			V
I_{RM}	Maximum Reverse Leakage Current	$V_R = 1200V$	$T_j = 25^\circ C$ $T_j = 175^\circ C$	70 130	400 800	μA
I_F	DC Forward Current		$T_c = 125^\circ C$	40		A
V_F	Diode Forward Voltage	$I_F = 40A$	$T_j = 25^\circ C$ $T_j = 175^\circ C$	1.5 2.2	1.8 3	V
Q_C	Total Capacitive Charge	$I_F = 40A, V_R = 1200V$ $di/dt = 1000A/\mu s$		260		nC
C	Total Capacitance	$f = 1MHz, V_R = 200V$ $f = 1MHz, V_R = 400V$		186 134		pF
R_{thJC}	Junction to Case Thermal Resistance				0.7	$^\circ C/W$

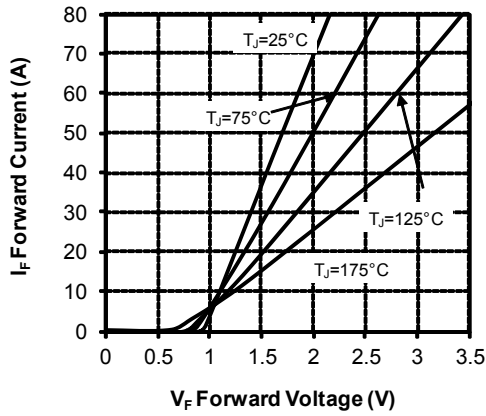


Typical SiC Diode Performance Curve

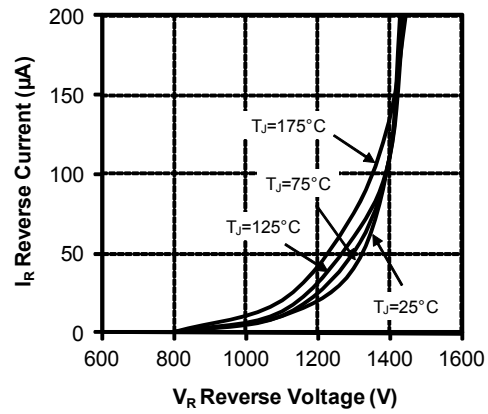
Maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration



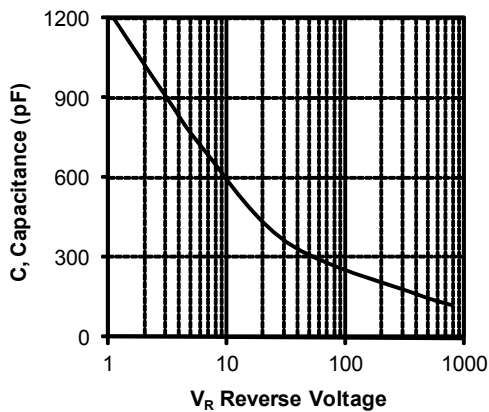
Forward Characteristics



Reverse Characteristics



Capacitance vs. Reverse Voltage



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